## Amendments to the Claims

The listing of claims will replace all prior versions, and listings, of claims in the application.

### Listing of Claims:

1. (Currently Amended) A method for reducing the slew rate of transition edges of a digital signal on a node of an integrated circuit, comprising:

connecting a first switchably conductive device characterized by a first threshold voltage of a given polarity between said node and a voltage source, said first switchably conductive device having a control input connected to a first input signal to allow current conduction from said voltage source to said node when a voltage level of said first input signal is equal to and greater than said first threshold voltage and to disallow said current conduction when said voltage level of said first input signal is less than said first threshold voltage;

connecting a second switchably conductive device independent from said first switchably conductive device and characterized by a second threshold voltage of said given polarity greater than said first threshold voltage between said node and said voltage source, said second switchably conductive device having a control input connected to a second input signal to allow current conduction from said voltage source to said node when a voltage level of said second input signal is equal to and greater than said second threshold voltage and to disallow said current conduction when said voltage level of said second input signal is less than said second threshold voltage; and

connecting a driving signal as said first input signal of said first switchably conductive device and as said second input signal of said second switchably conductive device.

2. (Currently Amended) A method in accordance with claim 1, comprising:

connecting between said node and said voltage source one or more additional independent switchably conductive devices each characterized by a

respective threshold voltage of said given polarity but different than said first threshold voltage, said second threshold voltage, and each other respective threshold voltage, each said one or more additional switchably conductive devices having a respective control input connected to a respective input signal to allow current conduction from said voltage source to said node when a voltage level of said respective input signal is equal to and greater than said respective threshold voltage and to disallow said current conduction when said voltage level of said respective input signal is less than said respective threshold voltage; and

connecting said driving signal as said respective input signal of said respective switch of each of said respective one or more additional switchably conductive devices.

3. (Currently Amended) An apparatus for reducing the slew rate of transition edges of a digital signal on a node of an integrated circuit, comprising:

a first switchably conductive device characterized by a first threshold voltage of a given polarity, said first switchably conductive device connected between said node and a voltage source and having a control input connected to a driving signal to allow current conduction from said voltage source to said node when a voltage level of said driving signal is equal to and greater than said first threshold voltage and to disallow said current conduction when said voltage level of said driving signal is less than said first threshold voltage; and

a second switchably conductive device independent from said first switchably conductive device characterized by a second threshold voltage of said given polarity greater than said first threshold voltage, said second switchably conductive device connected between said node and said voltage source and having a control input connected to said driving signal to allow current conduction from said voltage source to said node when a voltage level of said driving signal is equal to and greater than said second threshold voltage and to disallow said current conduction when said voltage level of said driving signal is less than said second threshold voltage.

4. (Previously Presented) An apparatus in accordance with claim 3, wherein said first switchably conductive device comprises a single field effect transistor (FET) and single second switchably conductive device comprises a single field effect transistor (FET).

5. (Currently Amended) An apparatus in accordance with claim 3, comprising:

one or more additional independent switchably conductive devices each characterized by a respective threshold voltage of said given polarity but different than said first threshold voltage, said second threshold voltage, and each other respective threshold voltage, each said one or more additional switchably conductive devices connected between said node and said voltage source and having a respective control input connected to said driving signal to allow current conduction from said voltage source to said node when said voltage level of said driving signal is equal to and greater than said respective threshold voltage and to disallow said current conduction when said voltage level of said driving signal is less than said respective threshold voltage.

6. (Currently Amended). An apparatus in accordance with claim ~~3~~ 5, wherein said first switchably conductive device comprises a single field effect transistor (FET) and single second switchably conductive device comprises a single field effect transistor (FET), and said one or more additional switchably conductive devices each comprises a single field effect transistor (FET).

7. (Currently Amended) A method for controlling the slew rate of transition edges of a digital signal on a node of an integrated circuit, said method comprising the steps of:

driving, with a driving signal, a first switchably conductive device characterized by a first threshold voltage of a given polarity and connected

between said node and a voltage source, said first switchably conductive device having a control input connected to said driving signal o allow current conduction from said voltage source to said node when a voltage level of said driving signal is equal to and greater than said first threshold voltage and to disallow said current conduction when said driving signal is less than said first threshold voltage;

driving, with said driving signal, a second switchably conductive device independent from said first switchably conductive device characterized by a second threshold voltage of said given polarity greater than said first threshold voltage and connected between said node and said voltage source, said second switchably conductive device having a control input connected to said driving signal to allow current conduction from said voltage source to said node when said voltage level of said driving signal is equal to and greater than said second threshold voltage and to disallow said current conduction when said voltage level of said driving signal is less than said second threshold voltage.

8-11. (Canceled)

12. (Currently Amended) A method for reducing the slew rate of transition edges of a digital signal on a node of an integrated circuit, comprising:

connecting a first switchably conductive device characterized by a first threshold voltage of a given polarity between said node and a voltage source, said first switchably conductive device having a control input connected to a first input signal to allow current conduction from said voltage source to said node when a voltage level of said first input signal is equal to and less than said first threshold voltage and to disallow said current conduction when said voltage level of said first input signal is greater than said first threshold voltage;

connecting a second switchably conductive device independent from said first switchably conductive device characterized by a second threshold voltage of said given polarity less than said first threshold voltage between said node and

said voltage source, said second switchably conductive device having a control input connected to a second input signal to allow current conduction from said voltage source to said node when a voltage level of said second input signal is equal to and less than said second threshold voltage and to disallow said current conduction when said voltage level of said second input signal is greater than said second threshold voltage; and

connecting a driving signal as said first input signal of said first switchably conductive device and as said second input signal of said second switchably conductive device.

13. (Currently Amended) A method in accordance with claim 12, comprising:

connecting between said node and said voltage source one or more additional independent switchably conductive devices each characterized by a respective threshold voltage of said given polarity but different than said first threshold voltage, said second threshold voltage, and each other respective threshold voltage, each said one or more additional switchably conductive devices having a respective control input connected to a respective input signal to allow current conduction from said voltage source to said node when a voltage level of said respective input signal is equal to and less than said respective threshold voltage and to disallow said current conduction when said voltage level of said respective input signal is greater than said respective threshold voltage; and

connecting said driving signal as said respective input signal of said respective switch of each of said respective one or more additional switchably conductive devices.

14. (Currently Amended) An apparatus for reducing the slew rate of transition edges of a digital signal on a node of an integrated circuit, comprising:

a first switchably conductive device characterized by a first threshold voltage of a given polarity, said first switchably conductive device connected between said node and voltage source and having a control input connected to a driving signal to allow current conduction from said voltage source to said node when a voltage level of said driving signal is equal to and less than said first threshold voltage and to disallow said current conduction when said voltage level of said driving signal is greater than said first threshold voltage; and

a second switchably conductive device independent from said first switchably conductive device characterized by a second threshold voltage of said given polarity less than said first threshold voltage, said second switchably conductive device connected between said node and said voltage source and having a control input connected to said driving signal to allow current conduction from said voltage source to said node when a voltage level of said driving signal is equal to and less than said second threshold voltage and to disallow said current conduction when said voltage level of said driving signal is greater than said second threshold voltage.

15. (Previously Presented) An apparatus in accordance with claim 14, wherein said first switchably conductive device comprises a single field effect transistor (FET) and single second switchably conductive device comprises a single field effect transistor (FET).

16. (Currently Amended) An apparatus in accordance with claim 14, comprising:

one or more additional independent switchably conductive devices each characterized by a respective threshold voltage of said given polarity but different than said first threshold voltage, said second threshold voltage, and each other respective threshold voltage, each said one or more additional switchably conductive devices connected between said node and said voltage source and having a respective control input connected to said driving signal to allow current

conduction from said voltage source to said node when said voltage level of said driving signal is equal to and less than said respective threshold voltage and to disallow said current conduction when said voltage level of said driving signal is greater than said respective threshold voltage.

17. (Currently Amended). An apparatus in accordance with claim ~~14~~ 16, wherein said first switchably conductive device comprises a single field effect transistor (FET) and single second switchably conductive device comprises a single field effect transistor (FET), and said one or more additional switchably conductive devices each comprises a single field effect transistor (FET).

18. (Currently Amended) A method for controlling the slew rate of transition edges of a digital signal on a node of an integrated circuit, said method comprising the steps of:

driving, with a driving signal, a first switchably conductive device characterized by a first threshold voltage of a given polarity and connected between said node and a voltage source, said first switchably conductive device having a control input connected to said driving signal to allow current conduction from said voltage source to said node when a voltage level of said driving signal is equal to and less than said first threshold voltage and to disallow said current conduction when said driving signal is greater than said first threshold voltage;

driving, with said driving signal, a second switchably conductive device independent from said first switchably conductive device characterized by a second threshold voltage of said given polarity less than said first threshold voltage and connected between said node and said voltage source, said second switchably conductive device having a control input connected to said driving signal to allow current conduction from said voltage source to said node when said voltage level of said driving signal is equal to and less than said second threshold voltage and to disallow said current conduction when said voltage level of said driving signal is greater than said second threshold voltage.

19. (Currently Amended) An apparatus for reducing the slew rate of transition edges of a digital signal on a node of an integrated circuit, comprising:

a first field effect transistor (FET) device characterized by a first threshold voltage of a given polarity, said first FET device having a source connected to a voltage source, a drain connected to said node, and a gate coupled to a driving signal; and

a second FET device characterized by a second threshold voltage of said given polarity and different than said first threshold voltage, said second FET device having a source connected to said voltage source, a drain connected to said node, and a gate coupled to said driving signal.

20. (Currently Amended) A method for reducing the slew rate of transition edges of a digital signal on a node of an integrated circuit, comprising:

connecting a source of a first field effect transistor (FET) device to a voltage source, a drain of said first FET to said node, and a gate of said first FET to a driving signal, said first FET characterized by a first threshold voltage of a given polarity; and

connecting a source of a second field effect transistor (FET) device to said voltage source, a drain of said second FET to said node, and a gate of said second FET to said driving signal, said first FET characterized by a second threshold voltage of said given polarity but different than said first threshold voltage.

21. (Currently Amended) A method for controlling the slew rate of transition edges of a digital signal on a node of an integrated circuit, said method comprising the steps of:

driving a gate of a first field effect transistor (FET) device with a driving signal, said first FET device characterized by a first threshold voltage of a given

polarity and having a source connected to voltage source and a drain connected to said node; and

driving a gate of a second field effect transistor (FET) device with a driving signal, said second FET device characterized by a second threshold voltage of said given polarity and different than said first threshold voltage and having a source connected to voltage source and a drain connected to said node.